
DISCRETE POWER DIODES and THYRISTORS

DATA BOOK

FAST RECOVERY DIODES

Stud Version

Features

- High power FAST recovery diode series
- 1.0 to 1.5 μ s recovery time
- High voltage ratings up to 1600V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Compression bonded encapsulation
- Stud version JEDEC DO-30
- Maximum junction temperature 125°C

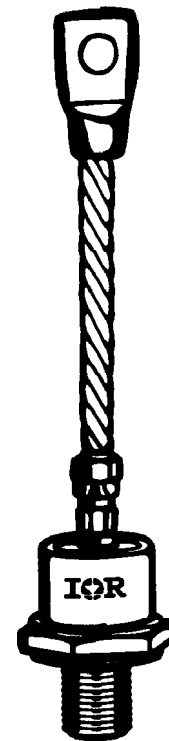
150A

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

Major Ratings and Characteristics

Parameters	SD153N/R	Units
$I_{F(AV)}$	150	A
@ T_C	85	°C
$I_{F(RMS)}$	235	A
I_{FSM} @ 50Hz	4280	A
@ 60Hz	4480	A
I^2t @ 50Hz	92	KA ² s
@ 60Hz	84	KA ² s
V_{RRM} range	400 to 1600	V
t_{rr} range	1.0 to 1.5	μ s
@ T_J	25	°C
T_J	- 40 to 125	°C



case style
DO-205AC (DO-30)

ELECTRICAL SPECIFICATIONS

Voltage Ratings

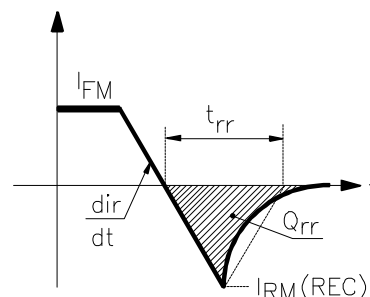
Type number	Voltage Code	V_{RRM} max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{RRM} max. $T_J = 125^\circ\text{C}$ mA
SD153N/R..S10	04	400	500	35
	08	800	900	
	10	1000	1100	
SD153N/R..S15	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

Forward Conduction

Parameter	SD153N/R	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	150	A	180° conduction, half sine wave.
	85	°C	
$I_{F(RMS)}$ Max. RMS current	235	A	DC @ 74°C case temperature
I_{FSM} Max. peak, one-cycle non-repetitive forward current	4280	A	t = 10ms No voltage reappplied
	4480		t = 8.3ms
	3600		t = 10ms 100% V_{RRM} reappplied
	3770		t = 8.3ms
I^2t Maximum I^2t for fusing	92	KA^2s	t = 10ms No voltage reappplied
	84		t = 8.3ms
	65		t = 10ms 100% V_{RRM} reappplied
	59		t = 8.3ms
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	916	$\text{KA}^2\sqrt{\text{s}}$	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level of threshold voltage	1.00	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
$V_{F(TO)2}$ High level of threshold voltage	1.46		$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
r_{f1} Low level of forward slope resistance	1.35	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
r_{f2} High level of forward slope resistance	0.52		$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
V_{FM} Max. forward voltage	1.55	V	$I_{pk} = 470 \text{ A}$, $T_J = 25^\circ\text{C}$, $t_p = 400 \mu\text{s}$ square pulse

Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ typical t_{rr} @ 25% I_{RRM} (μs)	Test conditions			Max. values @ $T_J = 125^\circ\text{C}$		
		I_{pk} Square Pulse (A)	di/dt (A/ μs)	V_r (V)	t_{rr} @ 25% I_{RRM} (μs)	Q_{rr} (μC)	I_{rr} (A)
S10	1.0	350	25	-30	1.6	21	27
S15	1.5				2.3	61	37



[查询"SD153N"供应商](#)

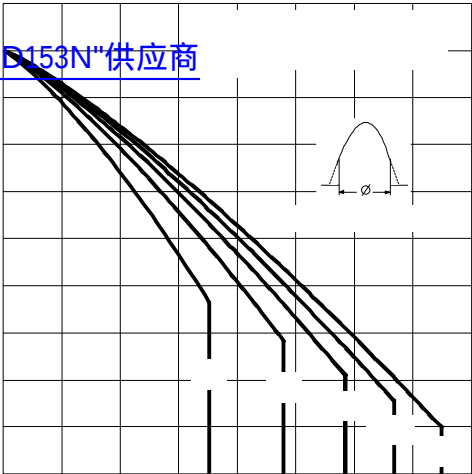


Fig. 1 - Current Ratings Characteristics

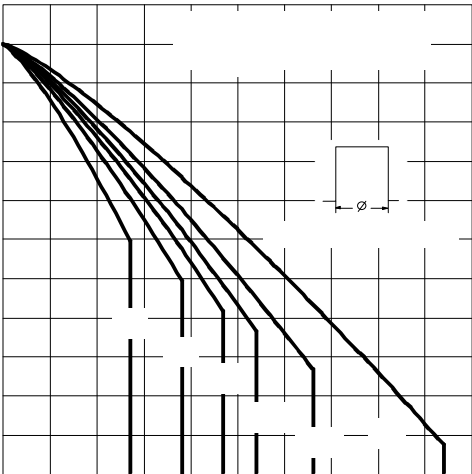


Fig. 2 - Current Ratings Characteristics

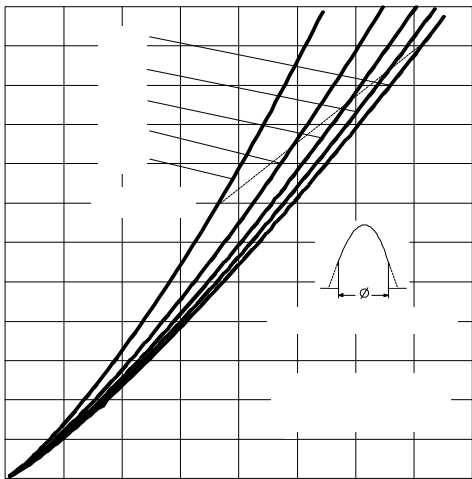


Fig. 3 - Forward Power Loss Characteristics

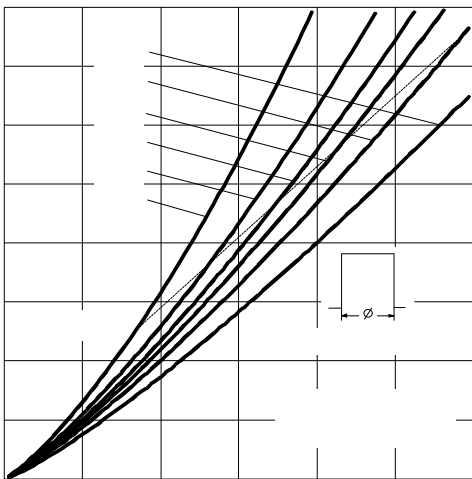


Fig. 4 - Forward Power Loss Characteristics

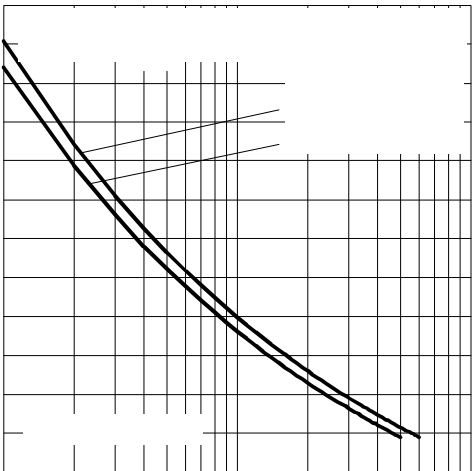


Fig. 5 - Maximum Non-repetitive Surge Current

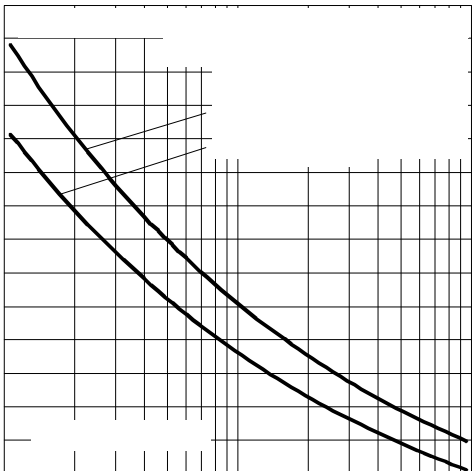


Fig. 6 - Maximum Non-repetitive Surge Current

[查询"SD153N"供应商](#)

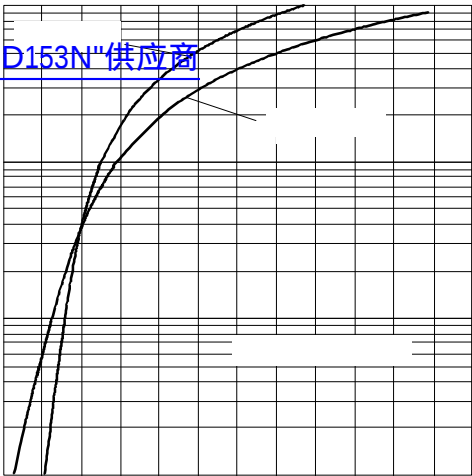


Fig. 7 - Forward Voltage Drop Characteristics

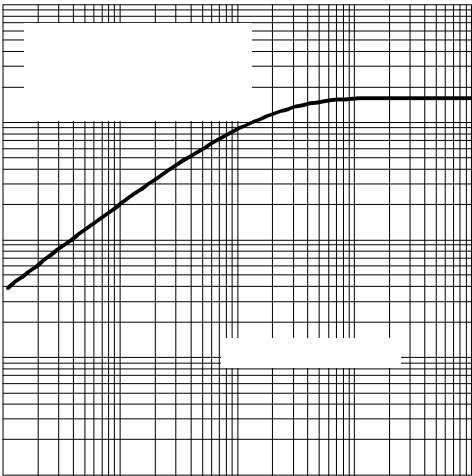


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

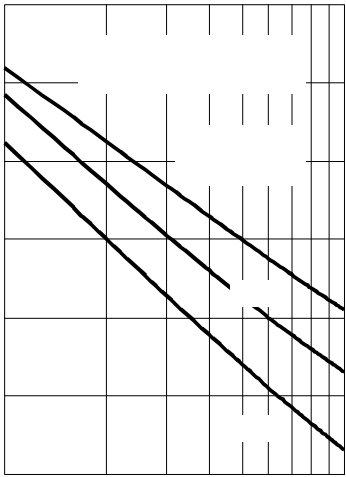


Fig. 9 - Recovery Time Characteristics

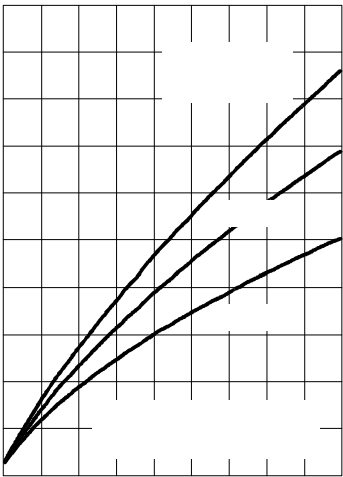


Fig. 10 - Recovery Charge Characteristics

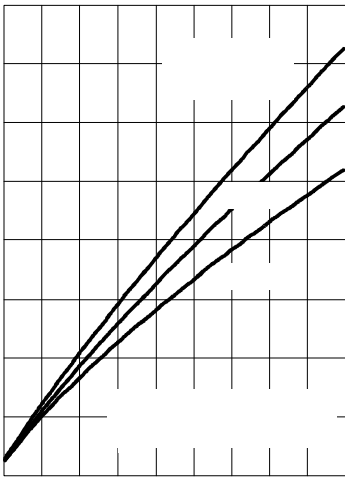


Fig. 11 - Recovery Current Characteristics

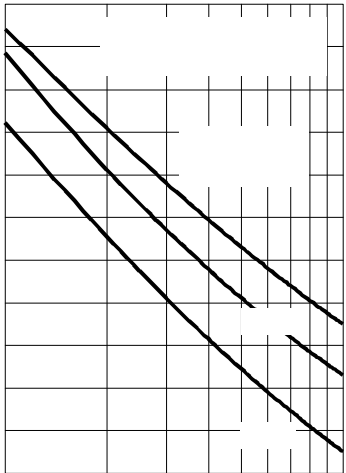


Fig. 12 - Recovery Time Characteristics

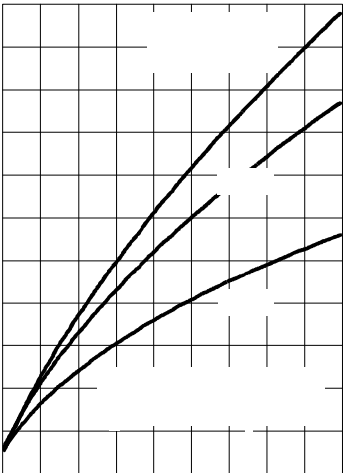


Fig. 13 - Recovery Charge Characteristics



Fig. 14 - Recovery Current Characteristics

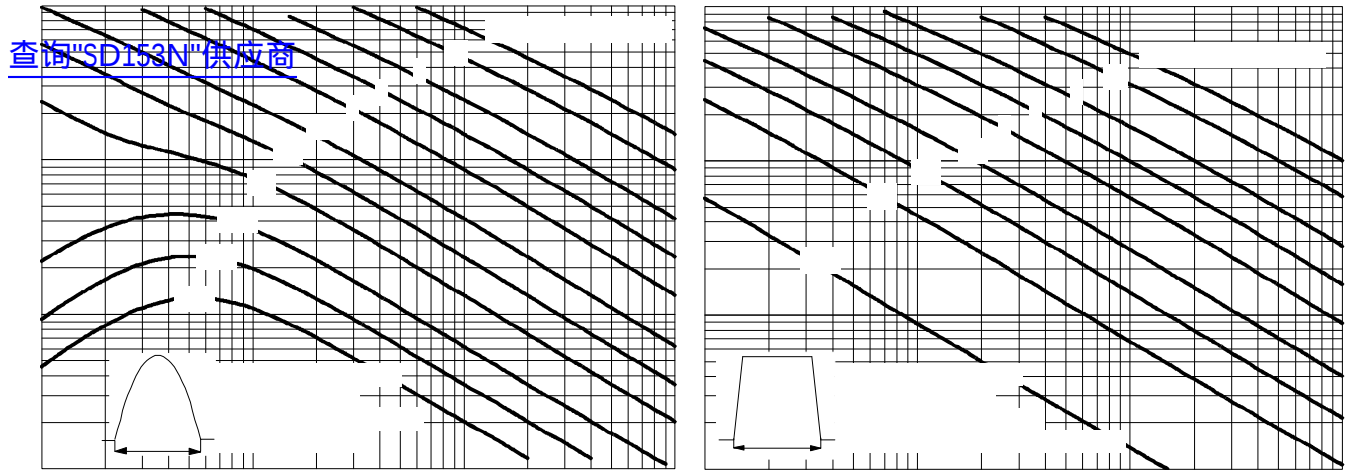


Fig. 15 - Maximum Total Energy Loss Per Pulse Characteristics

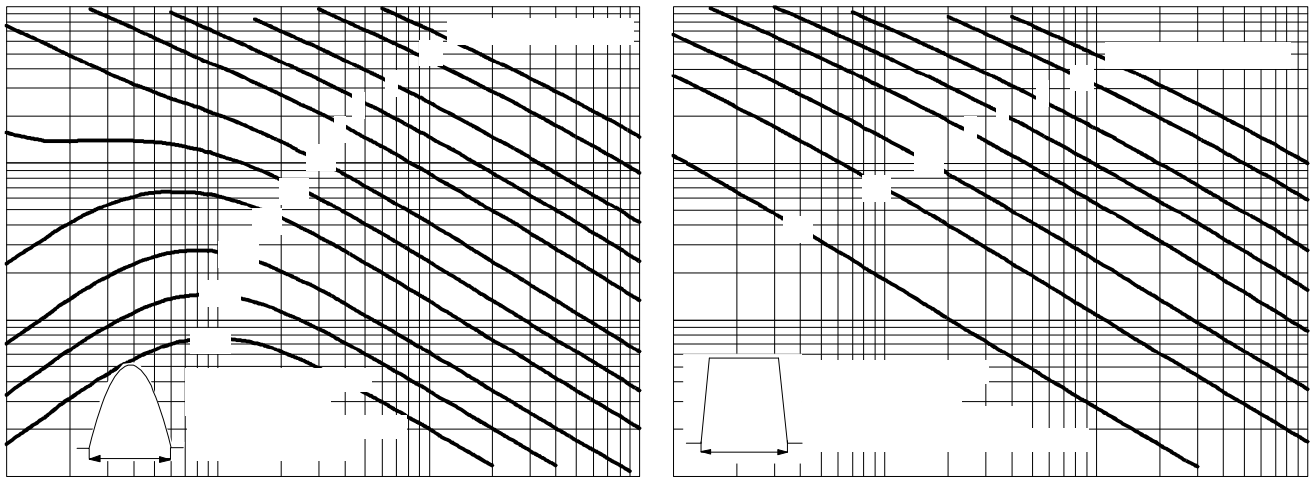


Fig. 16 - Maximum Total Energy Loss Per Pulse Characteristics

Thermal and Mechanical Specification

Parameter	SD153N/R	Units	Conditions
T _J Max. operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJC} Max. thermal resistance, junction to case	0.16	K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.10		Mounting surface, smooth, flat and greased
T Mounting torque ± 10%	15.5	Nm	Not lubricated threads
	13.5		Lubricated threads
wt Approximate weight	120	g	
Case style	DO-205AC (DO-30)		See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.011	0.012	K/W	T _J = T _J max.
120°	0.016	0.019		
90°	0.021	0.023		
60°	0.029	0.030		
30°	0.041	0.041		

Ordering Information Table

Device Code

SD153R16S15PBV

1

2

3

4

5

6

7

8

9

1

- Diode

2

- Essential part number

3

- 3 = Fast recovery

4

- N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)

5

- Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)

6

- t_{rr} code (see Recovery Characteristics table)

7

- P = Stud base DO-205AC (DO-30) 1/2" 20UNF-2A
M = Stud base DO-205AC (DO-30) M12 X 1.75

8

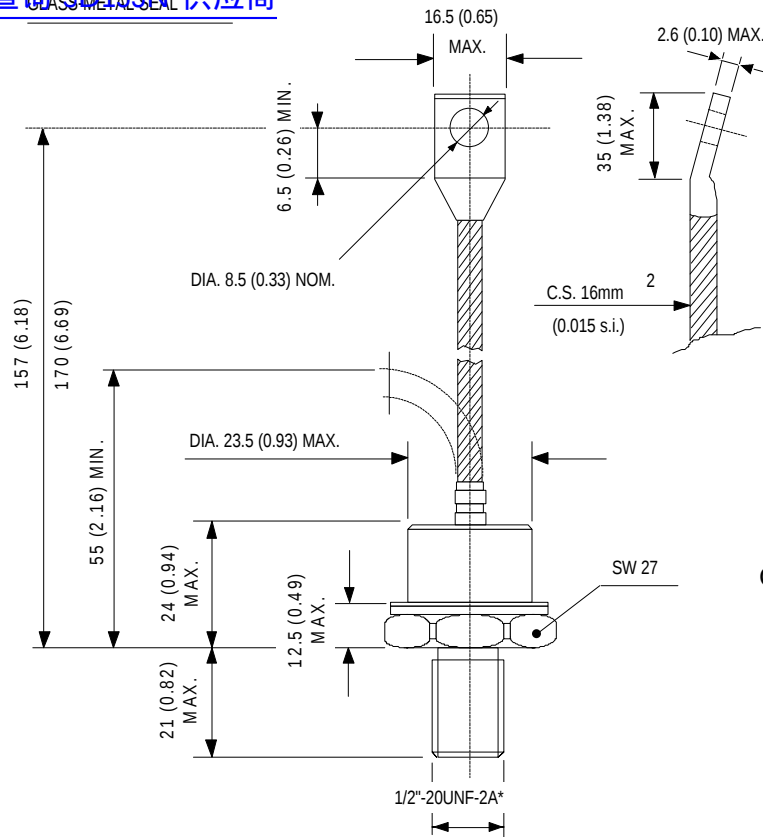
- B = Flag top terminals (for Cathode/ Anode Leads)
S = Isolated lead with silicone sleeve
(Red = Reverse Polarity; Blue = Normal Polarity)
None = Not isolated lead

9

- V = Glass-metal seal

Outline Table

[查询"SD153N"供应商](#)



DIA. 8.5 (0.33) NOM.

DIA. 23.5 (0.93) MAX.

C.S. 16mm
(0.015 s.i.)

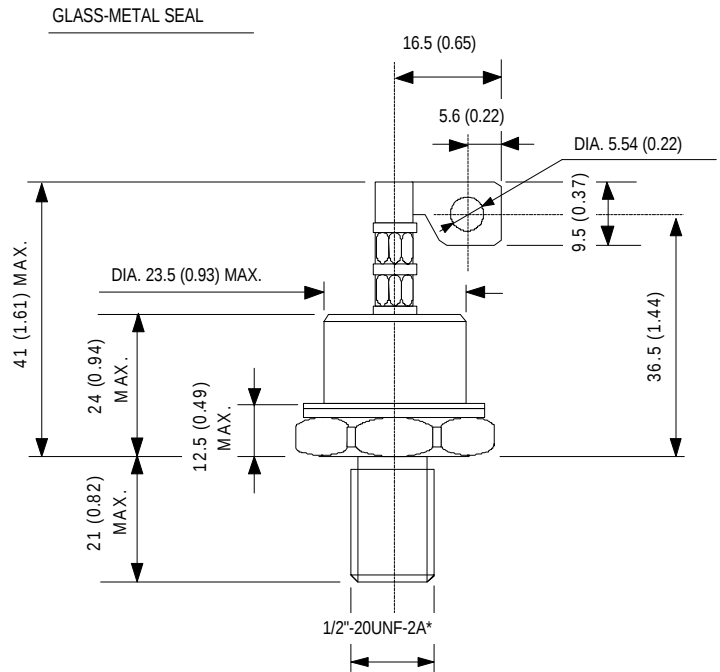
SW 27

1/2"-20UNF-2A*

* FOR METRIC DEVICE: M12 X 1.75

Conforms to JEDEC DO-205AC (DO-30)
All dimensions in millimeters (inches)

DO-205AC (DO-30) Flag
All dimensions in millimeters (inches)



DIA. 23.5 (0.93) MAX.

DIA. 5.54 (0.22)

1/2"-20UNF-2A*

*FOR METRIC DEVICE. M12 X 1.75

